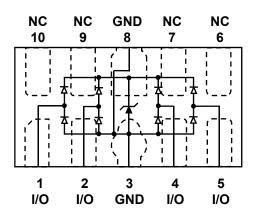


Low Capacitance TVS Array

Description

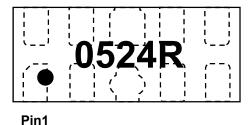
The PESDARC10N5VU is low capacitance transient voltage suppressor array for high speed data interface that designed to protect sensitive electronics from damage or latch-up due to ESD lightning, and other voltage induced transient events. All pins are rated to withstand 12KV ESD pulses using the IEC 61000-4-2 air discharge method, which can meet the requirement of level 4.



Circuit Diagram

Feature

- \triangleright 20W peak pulse power (t_P = 8/20µs)
- > DFN2510-10L Package
- ➤ Working voltage: 5.0V
- ➤ Low clamping voltage
- > Low capacitance
- > RoHS compliant
- ➤ Transient protection for data lines to IEC 61000-4-2(ESD) ±12KV(air), ±10KV(contact); IEC 61000-4-5 (Lightning) 5A (8/20us)



Marking (Top View)

Applications

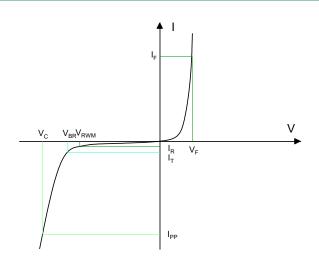
- ➤ USB 2.0,3.0 Power & Data Line Protection
- DVI & HDMI Port Protection
- Serial ATA Port Protection
- Mobile Handsets
- Digital Cameras and camcorders
- PDA & MP3 Players
- ➤ Digital TV and Set-top Boxes
- > Other Portable Electronic Components

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- ➤ Pure tin plating: 7 ~ 17 um
- ➤ Pin flatness:≤3mil

Electronics Parameter

Symbol	Parameter		
V_{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I _T		
I _T	Test Current		
I _{PP}	Maximum Reverse Peak Pulse Current		
V _C	Clamping Voltage @ I _{PP}		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		
I _F	Forward Current		
V _F	Forward Voltage @ I _F		



Electrical characteristics per line@25°C (unless otherwise specified)

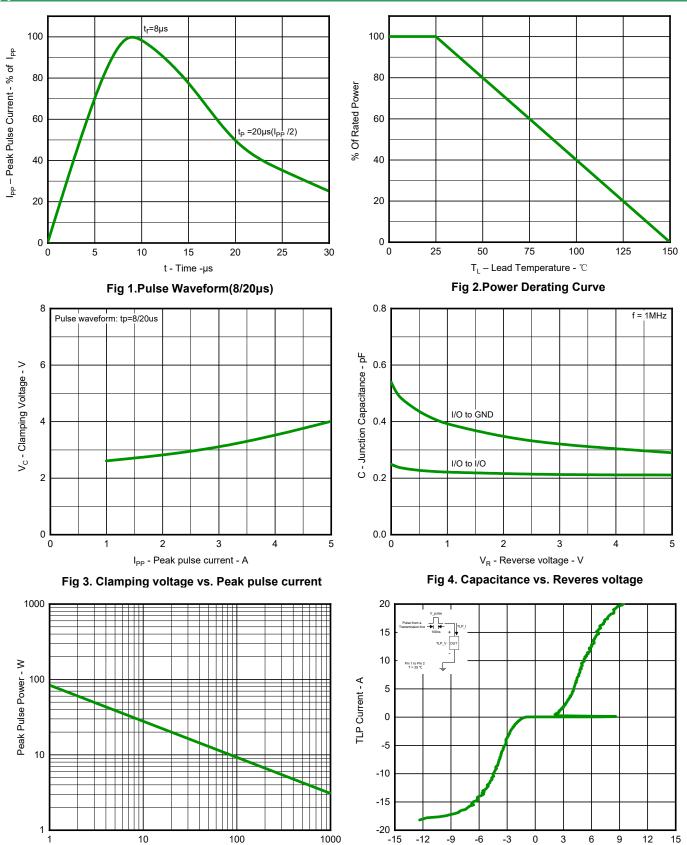
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}	-	-	-	5.0	V
Breakdown Voltage	V_{BR}	I _t = 1mA	5.6	-	8.0	V
Reverse Leakage Current	I _R	V _{RWM} = 5V	-	-	1.0	μA
Clamping Voltage ¹⁾	V _C	TLP = 16A, $t_p = 100 \text{ns}$	-	7.0	-	V
Dynamic resistance ¹⁾	R _{DYN}	-	-	0.25	-	Ω
Clamping Voltage ²⁾	V _C	$I_{PP} = 5A, t_{P} = 8/20 \mu s$	-	4.0	6.0	٧
Forward Voltage	V _F	I _F = 10mA	-	0.83	1.2	\
Capacitance Between IO and GND	6	\/ = 0\/f = 1MHz	-	0.55	0.7	pF
Capacitance Between IO and I/O	C _J	$V_R = 0V, f = 1MHz$	-	0.35	0.5	pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µs)	P _{PP}	20	W
Peak Pulse Current (t _P = 8/20μs)	I _{PP}	5.0	А
Lead Soldering Temperature	T _L	260 (10 sec)	°C
Junction and Storage Temperature Range	$T_{J,}T_{STG}$	-55~+150	°C
ESD Protection-Contact Discharge	V _{ESD}	±10	kV
ESD Protection-Air Discharge	V _{ESD}	±12	kV

^{1.}TLP parameter: Z_0 =50 Ω , t_p =100ns, t_r =2ns, averaging window from 70ns to 90ns. R_{DYN} is calculated from 4A to 16A. 2.Non-repetitive current pulse, according to IEC61000-4-5.

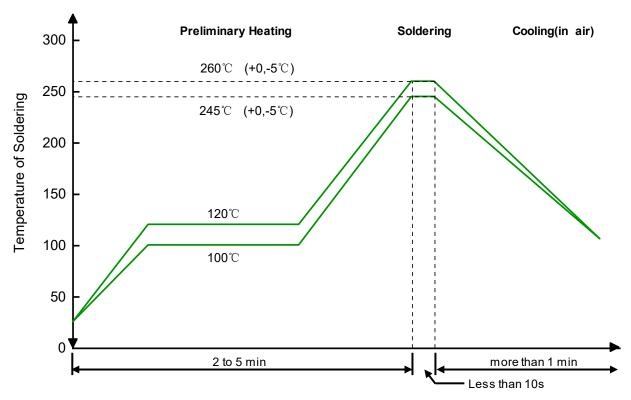
Typical Characteristics



 $\label{eq:pulse Duration - } \mu s$ Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

TLP Voltage - V Fig 6. TLP Measurement

Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

PCB Design

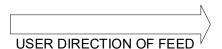
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

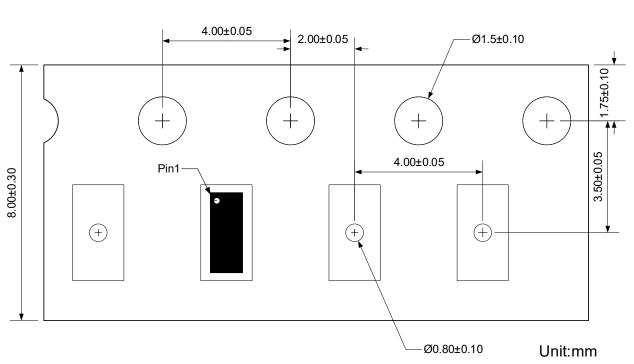
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

Ordering information

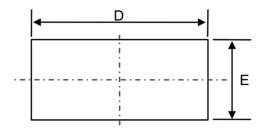
Device	evice Package		Shipping	
PESDARC10N5VU DFN2510-10L (Pb-Free)		7"	3000 / Tape & Reel	

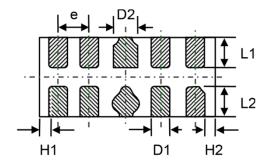
Load with information





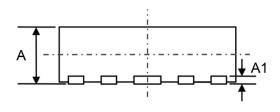
Product dimension (DFN2510-10L)





BOTTOM VIEW

TOP VIEW



SIDE VIEW

Dim	Millin	neters	Inches		
Dim	Min	Max	Min	Max	
Α	0.50	0.65	0.020	0.026	
A1	0.13 Ref.		0.005	Ref.	
D	2.40	2.60	0.094	0.102	
D1	0.15	0.25	0.006	0.010	
D2	0.35	0.45	0.014	0.018	
E	0.90	1.10	0.035	0.043	
е	0.50 Ref.		0.020 Ref.		
L1	0.30	0.46	0.012	0.018	
L2	0.30	0.46	0.012	0.018	
H1	0.075	0.175	0.003	0.007	
H2	0.075	0.175	0.003	0.007	

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